

#### Continental Device India Limited

An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





## PNP SILICON PLANAR TRANSISTOR

2N4036 TO-39



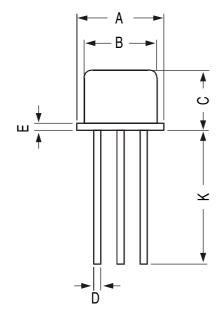
# **General Purpose Transistor**

## **ABSOLUTE MAXIMUM RATINGS**

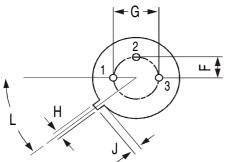
DESCRIPTION	SYMBOL	VALUE	UNIT
Collector -Emitter Voltage	VCEO	65	V
Collector -Base Voltage	VCBO	90	V
Emitter Base Voltage	VEBO	7.0	V
Base Current	IB	0.5	Α
Collector Current -Continuous	IC	1.0	Α
Power Dissipation @ Tc=25 deg C	PD	5.0	W
Linear Derating Factor		28.6	mW/deg C
Power Dissipation @ Ta=25 deg C	PD	1.0	W
Linear Derating Factor		5.72	mW/deg C
Operating & Storage Junction	Tj, Tstg	-65 to +200	deg C
Temperature Range			
Lead Temperature 1/16" from Case	TL	230	deg C
for 10 Seconds			
Thermal Resistance			
Junction to Case	Rth (j-c)	35	deg C/W

Juliculon to Gase	Kui (J-C)	33				ueg C/vv		
ELECTRICAL CHARACTERISTICS (Ta=25 deg C Unless Otherwise Specified)								
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT		
Collector -Emitter Voltage	VCEO	IC=10mA, IB=0	65	-		V		
Collector -Base Voltage	VCBO	IC=100uA, IE=0	90	-	-	V		
Collector Cut off Current	ICEX	VCE=85V, VBE=1.5V	-	-	0.1	mΑ		
	ICBO	VCB=90V, IE=0	-		1.0	uA		
Emitter Cut off Current	IEBO	VBE=7V, IC=0	-		10	uA		
DC Current Gain	hFE	0.1mA, VCE=10V	20	-	-			
		IC=150mA, VCE=2V	20		200			
		IC=150mA, VCE=10V	40	-	140			
		IC=500mA, VCE=10V	20		-			
Collector -Emitter (sat) Voltage	VCE(sat)	IC=150mA, IB=15mA	-		0.65	V		
Base -Emitter (sat) Voltage	VBE(sat)	IC=150mA, IB=15mA	-		1.4	V		
Small- Signal Characteristics								
Current Gain- High Frequency	Ihfel	IC=50mA,VCE=10V, f=20MHz	3.0	-	-			
Conitabio y Obana stanistica								
Switching Characteristics		154 45 440 450 4 1/05 001/						
Rise time	tr	IB1=15mA,IC=150mA, VCE=30V	-		70	ns		
Sorage time	ts	IB2=15mA,IC=150mA, VCE=30V	-		600	ns		
Fall time	tf	IB2=15mA,IC=150mA, VCE=30V	-		100	ns		
Turn-on time	ton	IC=150mA, VCE=30V, IB1=IB2=	_		110	ns		
Turn-off time	toff	15mA	-		700	ns		

### **TO-39 Metal Can Package**



	DIM	MIN	MAX
	Α	8.50	9.39
	В	7.74	8.50
	С	6.09	6.60
	D	0.40	0.53
_	Ε	-	0.88
All dimensions are in mm	F	2.41	2.66
ıre ir	G	4.82	5.33
ns a	Н	0.71	0.86
oisc J	0.73	1.02	
ime	K	12.70	1
All d	L	42 DEG	48 DEG
- '			





PIN CONFIGURATION

- 1. EMITTER
- 2. BASE
- 3. COLLECTOR

# **Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-39	500 pcs/polybag	540 gm/500 pcs	3" x 7.5" x 7.5"	20.0K	17" x 15" x 13.5"	32.0K	40 kgs

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Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India.

Telephone + 91-11-2579 6150, 5141 1112 Fax + 91-11-2579 5290, 5141 1119

email@cdil.com www.cdilsemi.com